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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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C	Complete if Known				
Application Number	10/654,561				
Filing Date	03 September 2003 (herewith)				
First Named Inventor	Shahram Abdollahi-Alibeik et al.				
Group Art Unit					
Examiner Name	1				
Attorney Docket Number	TRAM 1002-1				

			U.S. PATENT DOCI	JMENTS	
Examine Initials	Cite No.1	U.S. Patent Document Number Kind Code ² (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Refevant Passages or Relevant Figures Appear
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ろろ	B 1		WO 02/0824	53	T-RAM, Inc.	10-17-2002		
Nan	B2		WO 02/0825	04	T-RAM, Inc.	10-17-2002		T
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Attorney Docket Number

			U.S. PATENT DOCU	JMENTS	
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	~	F	oreign Patent Do	cument	Name of Patentee or	Date of Publication of	Pages, Columns, Lines,	Т
Examiner Initials	Cite No.1	Office ³	Number ⁴	Kind Code ^s (# known)	Applicant of Cited Document	Cited Document MM-DD-YYYY	Where Relevant Passages or Relevant Figures Appear	Te
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Substitute	e for form 14498.	/PTO		Co	emplete if Known
				Application Number	1
INFO	PRMATIC	D NC	ISCLOSURE	Filing Date	03 September 2003 (herewith)
STA	TEMEN	T BY	APPLICANT	First Named Inventor	Shahram Abdollahi-Alibeik et al.
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	(use as mai	ny sheets	as necessary)	Examiner Name	
Sheet	3	of	3	Attorney Docket Number	TRAM 1002-1

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Examiner Initials	Cite No. ¹	item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T
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